

4-8 GHz Low Noise Amplifier, 3.3v

General Description

The NBL00432 is a single biased (+3.3 V) low noise amplifier with less than 2 dB of noise figure operating between 4.0 GHz and 8.0 GHz. A thin film hybrid MIC process is used to achieve robust characteristics over temperature range -30°C to +70°C. The amplifier incorporates internally protected voltage regulator and can be biased in a wide range of DC voltage. Both input and output RF connectors are field replaceable SMA-F connector.



Performance 25 °C, Vcc = +3.3 V

Parameter	Min.	Тур.	Max.	Units
Frequency	4.0		8.0	GHz
Gain at room temperature	28	29		dB
Gain Flatness over all frequency range at room temperature		± 0.8	± 1.0	dB
Noise Figure at room temperature		1.7	2.2	dB
1 dB Compression Point at room temperature	10	13		dBm
Input VSWR			2.0 : 1	
Output VSWR			2.0 : 1	
DC supply voltage (Vcc)	+3.3		+16	V
Supplied Current		82	100	mA
Operating Temperature	-30		70	°C

Please Note: Reverse Polarity Protection Not Included.

No damage voltage range -0.3V to +16V

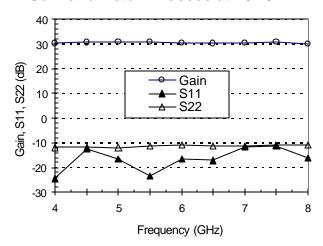
Customized Designs: For custom designs, including both electrical and mechanical, please contact us at sales@nextec-rf.com.



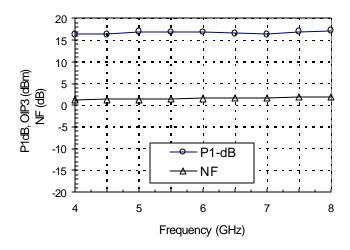
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Typical Test Data

Gain and Return Losses at 25 °C



P1-dB, Output IP3 and Noise Figure at 25 °C

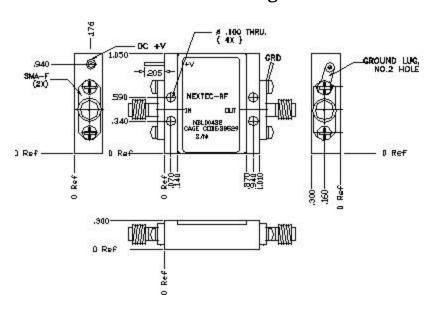


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Outline Drawing



(unit: inch)

Connector Description

RFin	RF input signal (replaceable SMA-F)	
RFout	RF output signal (replaceable SMA-F)	
Vcc	DC Supply Voltage (3.3V to 15V)	